

# L6925D

## HIGH EFFICIENCY MONOLITHIC SYNCHRONOUS STEP DOWN REGULATOR

## 1 FEATURES

- 2.7V TO 5.5V BATTERY INPUT RANGE
- HIGH EFFICIENCY: UP TO 95%
- INTERNAL SYNCHRONOUS SWITCH
- NO EXTERNAL SCHOTTKY REQUIRED
- EXTREMELY LOW QUIESCENT CURRENT
- 800mA MAX OUTPUT CURRENT
- ADJUSTABLE OUTPUT VOLTAGE FROM 0.6V
- LOW DROP-OUT OPERATION: UP TO100% DUTY CYCLE
- SELECTABLE LOW NOISE/LOW CONSUMPTION MODE AT LIGHT LOAD
- LOW BATTERY INPUT
- LOW BATTERY OUTPUT
- ±1% OUTPUT VOLTAGE ACCURACY
- CURRENT-MODE CONTROL
- 600kHz SWITCHING FREQUENCY
- EXTERNALLY SYNCHRONIZABLE FROM 500kHz TO 1.4MHz
- OVP
- SHORT CIRCUIT PROTECTION

## **1.1 APPLICATIONS**

- BATTERY-POWERED EQUIPMENTS
- PORTABLE INSTRUMENTS
- CELLULAR PHONES
- PDAs AND HAND HELD TERMINALS
- DSC
- GPS

#### Figure 2. Application Test Circuit

### Figure 1. Package



#### Table 1. Order Codes

Part Number	Package
L6925D	MSOP8 (Tube)
L6925D013TR	Tape & Reel

## 2 DESCRIPTION

The device is dc-dc monolithic regulator specifically designed to provide extremely high efficiency.

The device has on UVLO set at 2.7V cause it is particurarly thought for single Li-ion cell applications. Output voltage can be selected by an external divider down to 0.6V. Duty Cycle can saturate to 100% allowing low drop-out operation.

The device is based on a 600kHz fixed-frequency, current mode-architecture. Low Consumption Mode operation can be selected at light load conditions, allowing switching losses to be reduced. L6925D is externally synchronizable with a clock which makes it useful in noise-sensitive applications.

LBI pin can be used to have a LBO signal when the Battery voltage is lower than a preset value. Other features like, Overvoltage protection, Shortcircuit protection and Thermal Shutdown (150°C) are also present.



## Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit V	
V <sub>6</sub>	Input voltage	-0.3 to 6		
V5	Output switching voltage	-1 to V <sub>CC</sub>	V	
V <sub>1</sub> , V <sub>8</sub>	Low Battery Input, Low Battery Output	-0.3 to V <sub>CC</sub>	V	
V <sub>3</sub>	Feedback voltage	-0.3 to V <sub>CC</sub>	V	
V <sub>2</sub>	Error Amplifier Output Voltage	-0.3 to V <sub>CC</sub>	V	
V <sub>7</sub>	Syncronization / Mode Selector	-0.3 to V <sub>CC</sub>	V	
Ptot	Power dissipation at Tamb=70°C	0.45	W	
Tj	Junction operating temperature range	-40 to 150	°C	
T <sub>stg</sub>	Storage temperature range	-65 to 150	°C	
LX Pin	Maximum Withstanding Voltage Range Test Condition: CDF-	±1000	V	
Other pins	AEC-Q100-002- "Human Body Model" Acceptance Criteria: "Normal Performance'	±2000	V	

## Figure 3. Pin Connection



## Table 3. Thermal Data

Symbol	Parameter	Value	Unit
R <sub>th j-amb</sub>	Thermal Resistance Junction to Ambient	180	°C/W

### **Table 4. Pin Functions**

Ν	Name	Description					
1	LBI	Battery low voltage detector input. The internal threshold is set to 0.6V. The external threshold can be adjusted by using an external resistor divider.					
2	COMP	Error amplifier output. Compensate it with a 220pF capacitor					
3	VFB	Error amplifier input. The output voltage can be adjusted by using an external resistor divider connected to this pin ( $V_{FB} = 0.6V$ ).					
4	GND	Ground.					
5	LX	Switch node connection to the inductor.					
6	VCC	Input voltage.					
7	SYNC	This pin allows to select Low Noise/ Low Consumption Mode or to sychronize the device.					
8	LBO	Battery low voltage detector output. If the voltage at the LBI pin drops below the internal thrshold, LBO goes low. The LBO is an open drain output. A pull_up resistor should be connected between the pin and the output voltage					

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>cc</sub>	Operating input voltage	After Turn On	2.7		5.5	V
V <sub>cc ON</sub>	Turn On threshold			2.8		V
$V_{ccOFF}$	Turn Off threshold			2.65		V
V <sub>cc hys</sub>	Hysteresis			150		mV
Rp	High side Ron	$V_{cc} = 3.6V, I_{lx} = 100mA$		240		mΩ
R <sub>n</sub>	Low side Ron	$V_{cc} = 3.6V, I_{lx} = 100mA$		215		mΩ
l <sub>lim</sub>	Peak current limit	V <sub>cc</sub> = 3.6V		1.2		А
	Valley current limit	V <sub>cc</sub> = 3.6V		1.4		А
Vout	Output voltage range		0.6		Vcc	V
f <sub>osc</sub>	Oscillator frequency			600		KHz
f <sub>sync</sub>	Sync mode clock (*)		500		1400	KHz
DC CHARA	CTERISTICS	1	1	L	<u> </u>	
Ιq	Quiescent current (low noise mode)	$V_{sync} = 0V$ , no load, $V_{FB} > 0.6V$		230		μA
	Quiescent current (low cunsumption mode)	$V_{sync} = V_{cc}$ , no load, $V_{FB} > 0.6V$		25		μΑ
I <sub>sh</sub>	Shutdown current	V <sub>cc</sub> < 2.7V, V <sub>FB</sub> > 0.6V		0.2		μΑ
I <sub>IX</sub>	LX leakage current (*)	$V_{cc}$ < 2.7V, $V_{LX}$ = $V_{cc}$		1		μA
		$V_{cc}$ < 2.7V, $V_{LX}$ = 0V		1		μΑ
ERROR AM	PLIFIER CHARACTERISTICS	ł				
V <sub>fb</sub>	Voltage feedback		0.593	0.6	0.607	V
I <sub>fb</sub>	Feedback input current (*)	V <sub>FB</sub> = 0.6V		25		nA
SYNC/MOD	E FUNCTION	ł				
V <sub>sync_H</sub>	Sync mode threshold high				1.3	V
V <sub>sync_L</sub>	Sync mode threshold low		0.5			V
LB SECTIO	N	1			1 1	
$V_{LBI}$	LBI Threshold			0.6		V
V <sub>LBO</sub>	LBO Logic Low	$\label{eq:lsink} \begin{array}{l} I_{sink} = 1 \text{mA}, \ V_{cc} = 3.6 \text{V}, \\ V_{LBI} < 0.6 \text{V} \end{array}$		0.2	0.4	V
I <sub>LK-LBO</sub>	LBO Leakage Current (*)	$V_{\overline{LBO}} = 3.6V, V_{CC} = 3.6V, V_{LBI} > 0.6V$			50	nA
PROTECTIO	DNS	1			1 1	
HOVP	Hard overvoltage threshold			10		%Vou

Table 5. ELECTRICAL CHARACTERISTICS (T<sub>J</sub> =  $25^{\circ}$ C, V<sub>CC</sub> = 3.6V unless otherwise specified)

(\*) Guaranteed by design

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## Figure 4. MSOP8 Mechanical Data & Package Dimensions

DIM.	mm			inch			
DINI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	OUTLINE AND MECHANICAL DATA
А			1.10			0.043	
A1	0.050		0.150	0.002		0.006	
A2	0.750	0.850	0.950	0.03	0.033	0.037	
b	0.250		0.400	0.010		0.016	
С	0.130		0.230	0.005		0.009	
D (1)	2.900	3.000	3.100	0.114	0.118	0.122	SSSN
Е	4.650	4.900	5.150	0.183	0.193	0.20	
E1 (1)	2.900	3.000	3.100	0.114	0.118	0.122	
е		0.650			0.026		
L	0.400	0.550	0.700	0.016	0.022	0.028	
L1		0.950			0.037		
k		C	° (min.)	6° (max	.)		
aaa			0.100			0.004	MSOP8
PIN 1 IDENTIFICATION							

## Table 6. Revision History

Date	Revision	Description of Changes
January 2004 2		First Issue in EDOCS DMS
September 2004 3		Changed Style-sheet and Table 2

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